## **Electronic Supplementary Information**

## Growth of Copper Oxide Nanocrystals in Metallic Nanotube for High Performance Battery Anode

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SUPPORTING FIGURES



Figure S1. HRTEM images of the vacancies generated at the Cu/CuO interface.



**Figure S2.** For reaction temperatures between 60 °C and 300 °C, the fundamental mechanisms would not change while only the reaction rate increases. Changing the reaction temperature therefore only results in the formation of hollow nanostructures throughout the entire NW instead of the desired semi-hollow structures. a) TEM images of CuO nanostructure with intermittent columns obtained after exposure process at lower temperature (50 °C). b) HRTEM image of selected area in a, which reveals discontinuous outer walls. c) TEM images of CuO NT after exposure process at higher temperature (100 °C). d) HRTEM image of a section from CuO NT.



**Figure S3.** a) XRD patterns of pristine NWs (red), sample after oxidation process (purple) and final product after  $H_2$  plasma treatment (blue). b, c) Corresponding XPS spectra of the Cu 2p and O 1s regions of these samples, respectively.



**Figure S4.** EDS spectra captured from the side wall region and NP region of the CuO-NPs@Cu NT as indicated in position 1 and 2.



**Figure S5.** High-resolution TEM images reveal the porosity of degraded walls: a) CuO NT; b) CuO-NPs@CuO NT. Scale bars are 5 nm. The insets show their corresponding SAED patterns and bright field TEM image of the corresponding incomplete tube structure (scale bars: 50 nm).



**Figure S6.** a) Cell impedance tests of the CuO-NPs@Cu NT electrode after 1st, 1oth, 5oth, 1ooth, 15oth and 20oth deep cycles. b-d) Electrochemical impedance spectroscopy of b) CuO NPs, c) CuO NT, and d) CuO-NPs@CuO NT anodes after different cycles. e) Comparison of electrochemical impedance spectroscopies between CuO-NPs@Cu NT electrode and reference electrodes after cycling tests.



**Figure S7.** A digital photo of CuO-NPs@Cu NTs solution (30 grams, dispersed in 400 mL methanol) in a 1 L glass container.



**Figure S8.** Cyclic voltammograms (CV) of CuO-NPs@Cu NT cell cycled between 0.02~3 V vs. Li at a scan rate of 5 mV/s. This result reveals that the first scan curve differed significantly from subsequent four cycles, and the overlapping of  $2^{nd} \sim 5^{th}$  cycling traces is noted during both cathodic and anodic sweeps, which corresponds to the stability of CuO during lithium cycling. In the cathodic sweep the cell showed a weaker broad peak ~2.17 V vs. Li which corresponds to the solid solution formation (Li<sub>x</sub>CuO). Another two sharp peaks around ~1.29 and ~0.38V vs. Li are associated with the generation of Cu<sub>2</sub>O, following further reduction into Cu° and amorphous Li<sub>2</sub>O. This is consistent with the galvanostatic charge/discharge voltage profiles illustrated in Figure 3c.

Type of CuO-based	Reversible	Capacity fading	Number of	C-rate or	Ref.
nanostructures	capacities for first	after cyclic test	cycles	current density	
	(mAhg <sup>-1</sup> )	(mAhg <sup>-1</sup> per cycle)			
CuO	657	10.85	20	134 mAg <sup>-1</sup>	1
nanodisc/MWCNT					
CuO hollow	750	<3	50	0.2 C	2
microspheres					
CuO/C hollow spheres	560	2.4	50	100 mAg-1	3
CuO hierarchical	~560	13	20	0.1 C	4
hollow					
micro/nanostructures					
Pillow shaped CuO	~370	1	50	67 mAg <sup>-1</sup> (0.1 C)	5
Ultrafine CuO NWs	680	7	30	67 mAg <sup>-1</sup> (0.1 C)	6
CuO nanoribbons	495	-0.41	275	100 mAg-1	7
CuO/graphene	561	2.76	50	67 mAg-1	8
CuO NFs	453	0.26	100	100 mAg-1	9
Cu@Cu <sub>2</sub> O@CuO NS-	674	0.21	100	100 mAg-1	10
NWs					
CuO-HM	525.2	<0.2	500	67 mAg-1	11
CuO/Cu/C NFs	572	0.03	500	500 mAg-1	12
CuO-NPs@Cu NT	607	0.18	200	100 mAg-1	This
					study

Table S1. Comparison of various CuO-based nanostructures electrochemical per	rformances a	s anode
for Li-ion battery		

NW-nanowire; NS-nanosheet; MWCNT- multi walled carbon nanotube; NF-nanofiber; HMhierarchical CuO mesocrystals.

En fort butter j					
Type of Cu <sub>x</sub> O-based	minimum	Capacities at	maximum	Capacities at	Ref.
nanostructures	current density	minimum current	current density	maximum	
	(mAg <sup>-1</sup> )	density (mAhg-1)	(mAg <sup>-1</sup> )	current density	
				(mAhg <sup>-1</sup> )	
porous CuO NRs	300	654	3600	410	13
$CuO/Cu_2O$ hollow	100	480	1600	130	14
polyhedrons					
CuO NFs	100	453	222	167	9
MOF derived	50	600	2000	210	15
CuO nanostructures					
CuO/C hollow spheres	100	560	1000	165	3
Ultrafine CuO NWs	67	760	1072	420	6
CuO nanoribbons	100	594	800	332	7
mesoporous CuO	120	590	18000	120	16
particles/CNT					
CuO/Cu/C NFs	500	561	6000	<sup>2</sup> 35	12
CuO-NPs@Cu NT	100	607	15000	175	This
					study

**Table S2.** Comparison of various CuO-based nanostructures rate capacity performances as anode for Li-ion battery

NRs-nanorods; NFs-nanofibers; NWs-nanowires; NS-nanosheet; CNT-carbon nanotube

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